KNU 검출기학교 2024

SiPM, Preamp, DAQ

김상열

노티스

Why Electronics?

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Detector + Electronics + Analysis = Experiment
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Detector + Electronics + X = Development
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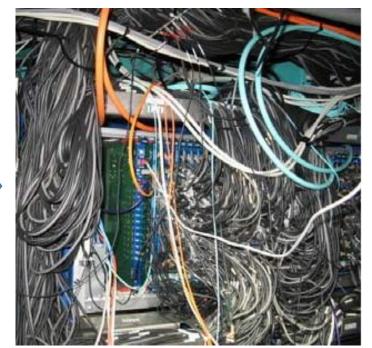
X + Electronics + Analysis = Not Bad?

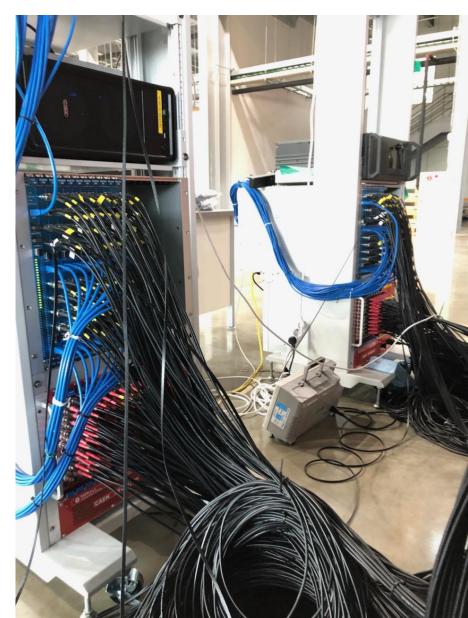
Detector + X + Analysis = ????











We will see:

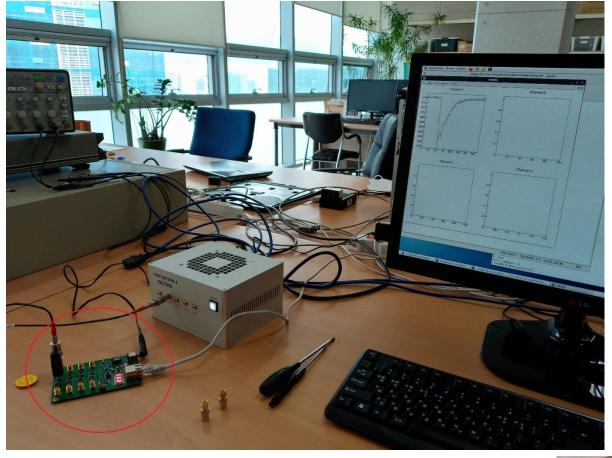
1. What electronics are used?

2. How they work?

3. How to make them?

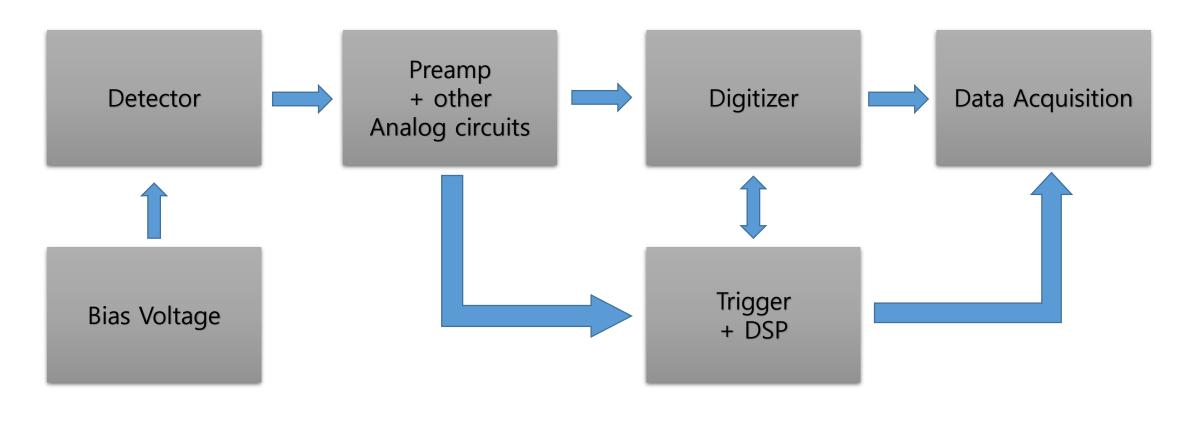
4. Where to sell?

Goal:



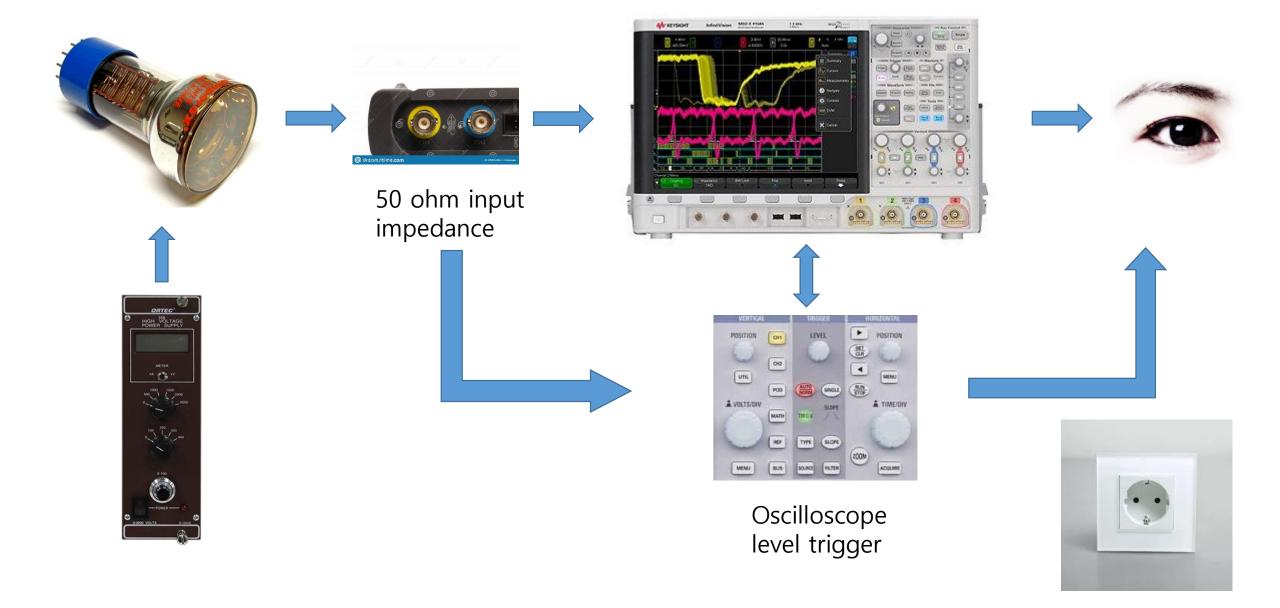


Electronics for High energy or Nuclear physics experiment



Power Supply

Frequently used example



Signal from some detectors



PMT, SiPM...: gain ~ 10^6

-> ~ 10^10 electrons/MeV

= ~ nC/MeV



Wire chamber, GEM...: gain ~ 10^2~3

 $-> \sim 10^6 \sim 7$ electrons/MeV

= ~ pC/MeV

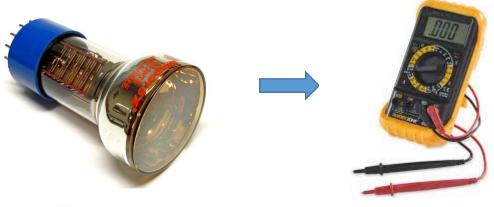


Photodiode, Ion chamber...: gain ~ 1

-> ~ 10^3~5 electrons/MeV

= ~ fC/MeV

How to measure signal



Typical detector's capacitance = $10 \sim 1000 \text{ pF}$ and V = Q/C



 \sim nC/100 pF/MeV = \sim V/MeV (OK)

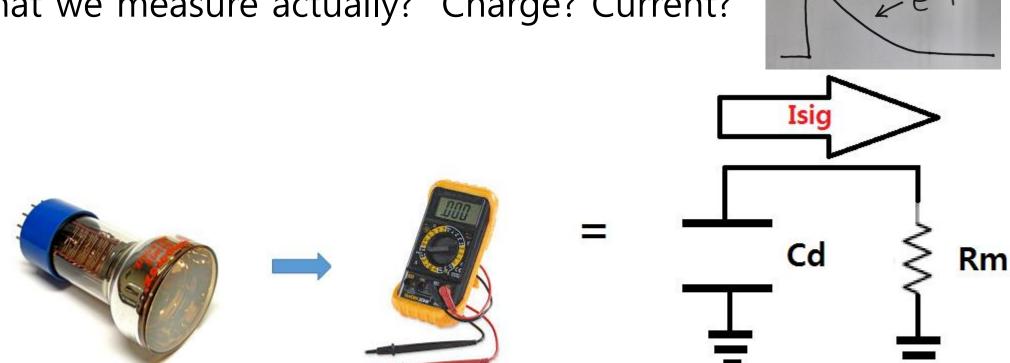


 \sim pC/100 pF/MeV = \sim mV/MeV (?)



 \sim fC/100 pF/MeV = \sim uV/MeV (X)

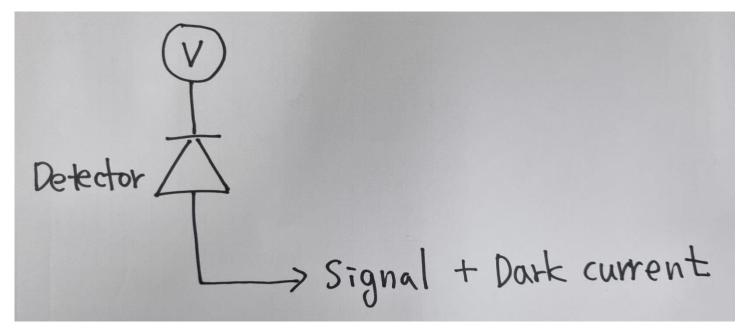
What we measure actually? Charge? Current?



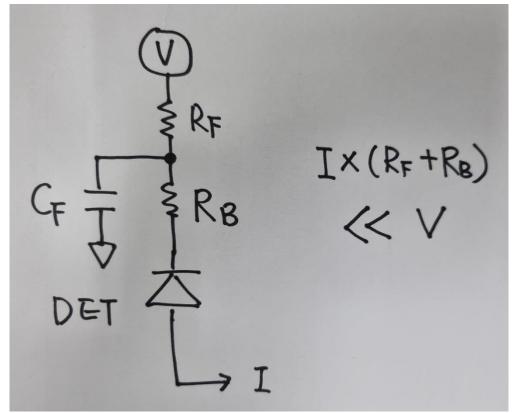
When Idet(detector current) is very fast, Isig = Qdet x exp(-t/T) where $T = Cd \times Rm = 100 \text{ pF} \times 10 \text{ Mohm}$ = ~ ms -> very long!

Detector signal:

Where it comes from? = Bias Voltage Source (few ~ 10,000 V)

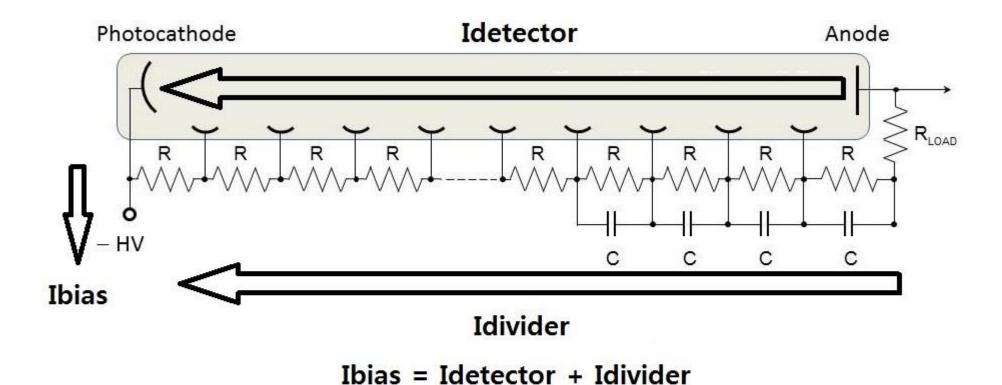


Ibias(max) > Isig + Idark Isig = Signal x Count rate



Bias Filter

PMT example



Usually Idivider >> Idetector (100 times or greater)

Bias voltage supplier should supply



If count rate = \sim 100 kcps (when no Dark current)

PMT : nC x 100 kcps x (10 \sim 100 : Divider) = 10 uA -> 1 mA @ a few kV -> W

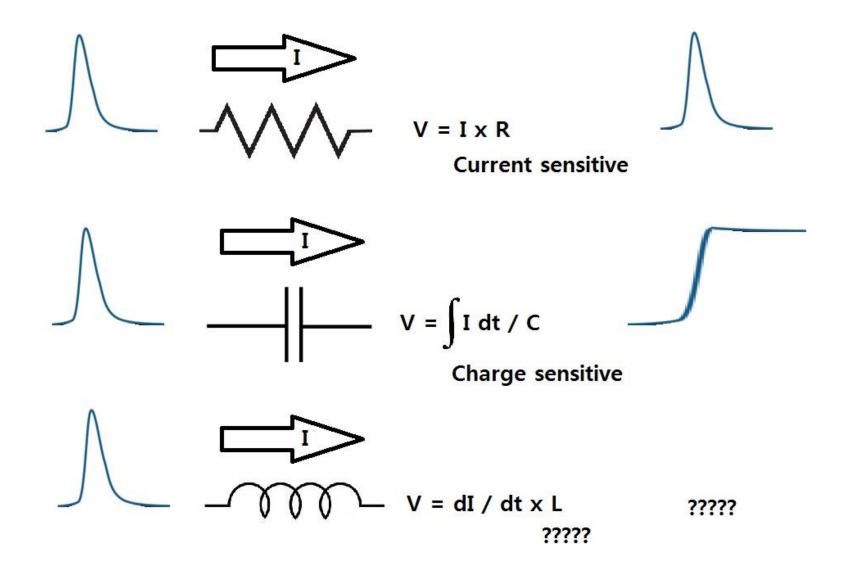
SiPM : nC x 100 kcps = $10 \text{ uA} \otimes 20 \sim 60 \text{ V} -> \text{ mW}$

Wire chamber, GEM... : pC x 100 kcps = $0.1 \text{ uA} \otimes \text{kV} -> \text{mW}$

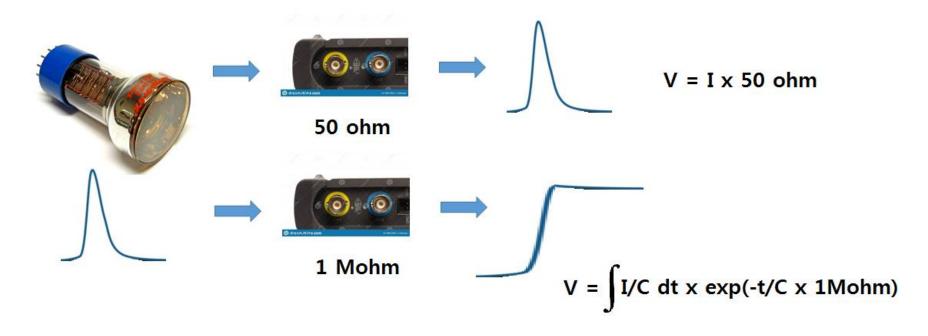


Photodiode, Ion chamber... : fC x 100 kcps = \sim 1 nA @ a few \sim kV -> uW

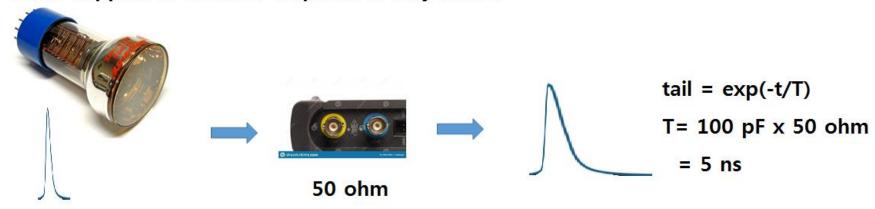
First thing to do:
Preamplifier converts Idet to Voltage signal.



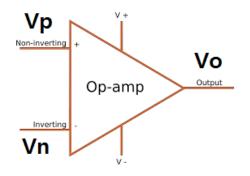
Take a look at PMT oscilloscope shot again



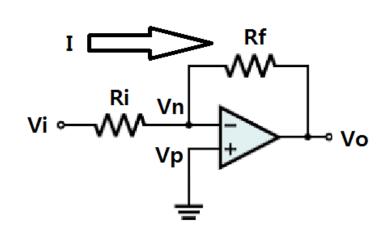
What happens if detector response is very short?



OpAmp basics



Vo = $A \times (Vp - Vn)$ where A is very large



$$Vp = 0$$

$$Vn = Vi - Ri \times I$$

$$Vo = Vn - Rf \times I$$

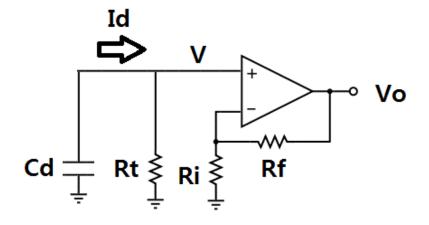
$$= A \times (Vp - Vn)$$

$$V0 = -Vi \times \frac{Rf}{Ri} \times \frac{1}{1 + [(1 + Rf/Ri) / A]}$$

$$= -Vi \times Rf/Ri$$

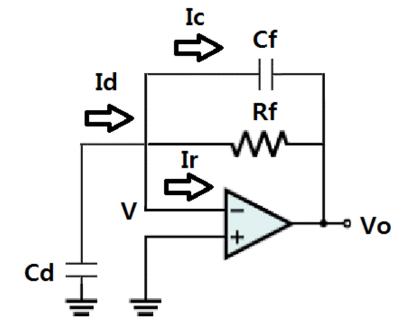
Similary, Vo = Vi x (1 + Rf/Ri)

Current Sensitive Preamp

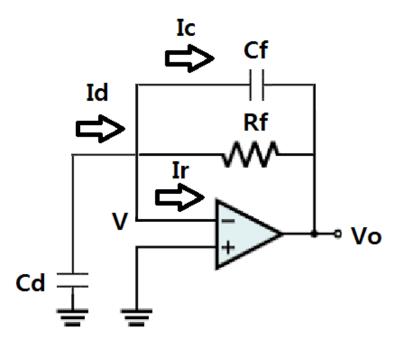


$$V = Qd / Cd = Id \times Rt = -dQd/dt \times Rt$$

 $Qd = Q \times exp(-t/Rt \times Cd)$
 $Vo = (1 + Rf/Ri) \times Q/Cd \times exp(-t/Rt \times Cd)$

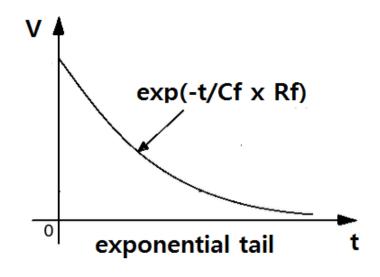


Charge Sensitive Preamp

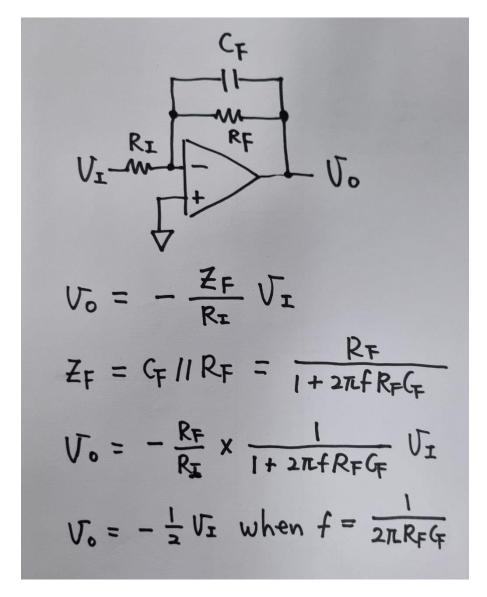


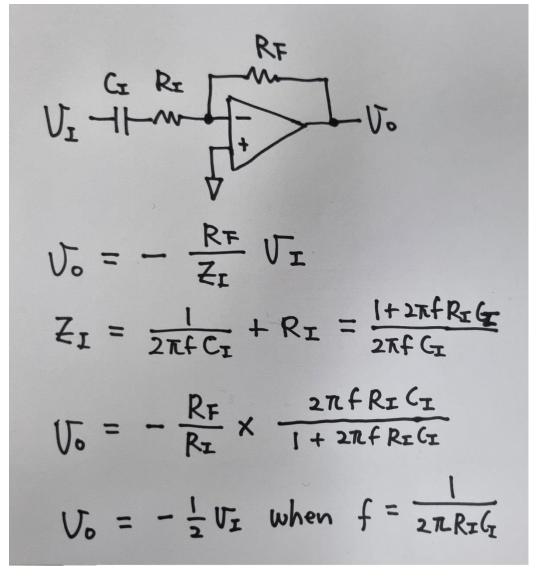
If Ic >> Ir, Ic = Id
$$V - V0 = -V = \int Ir \ dt \times 1/Cf$$

$$Vo = -1/Cf \times \int Id \ dt = -Qd/Cf$$



Filter: Modify preamplifier pulse to better shape for later stage

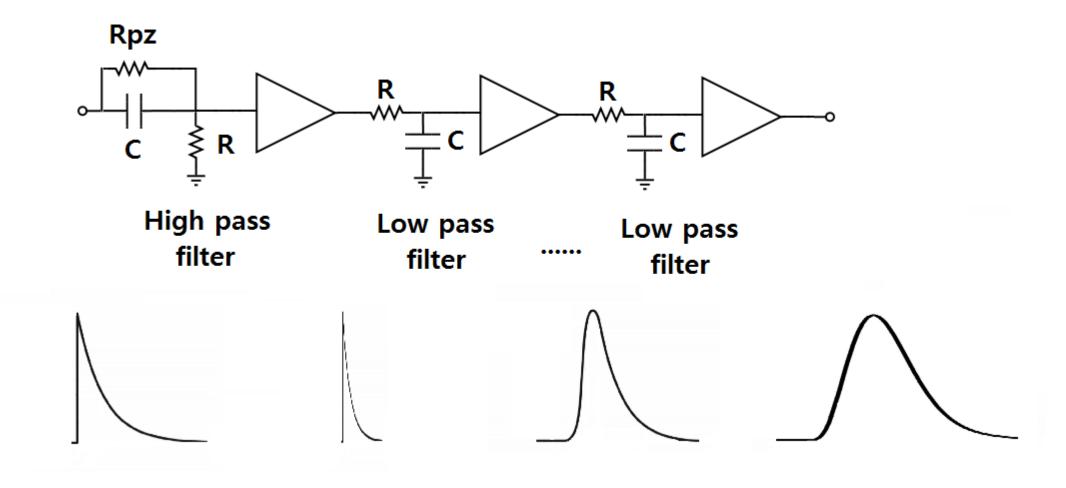




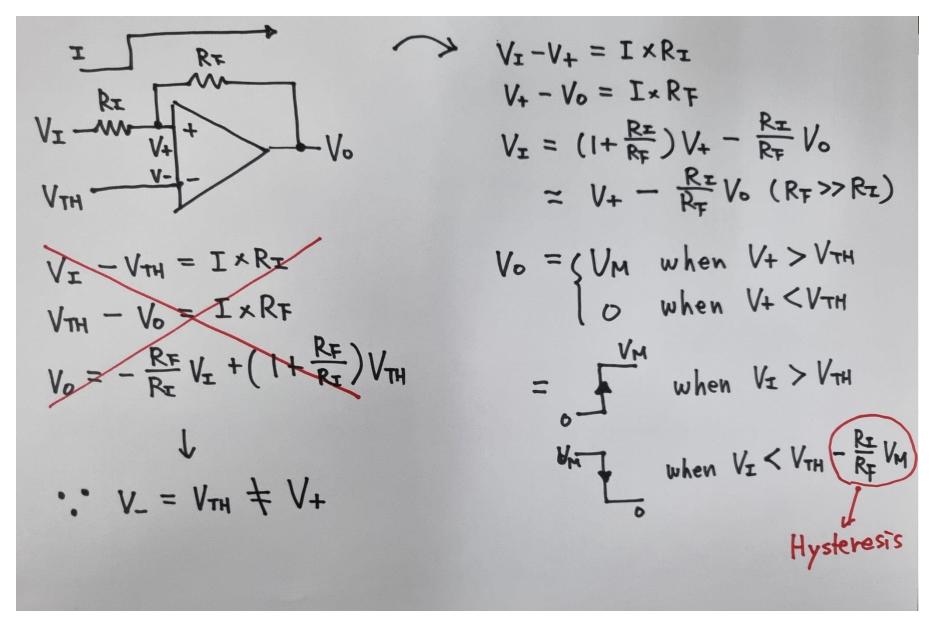
Low Pass Filter

High Pass Filter

Example of Shaping Amplifier: next to Charge sensitive preamplifier

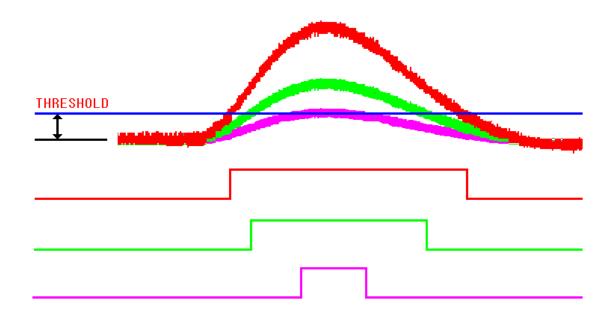


Voltage Comparator



Discriminator

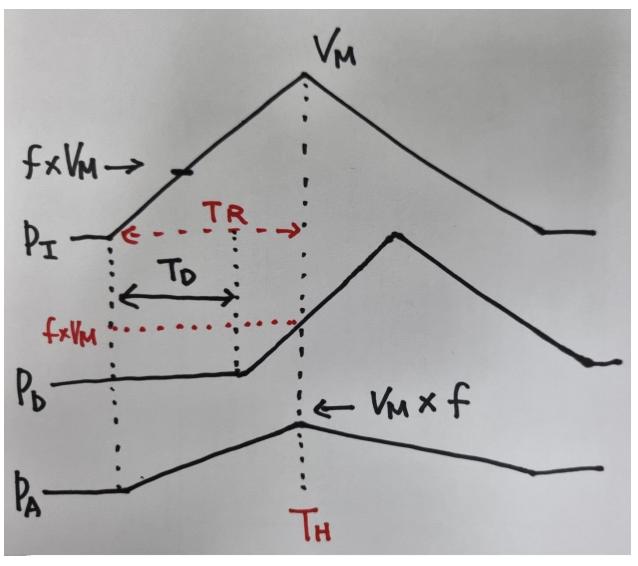
- 1. To discriminate noise
- 2. To get pulse timing



Leading edge discriminator

- 1. Simple
- 2. Large time walk

Constant Fraction Discriminator



Input pulse is fan out to

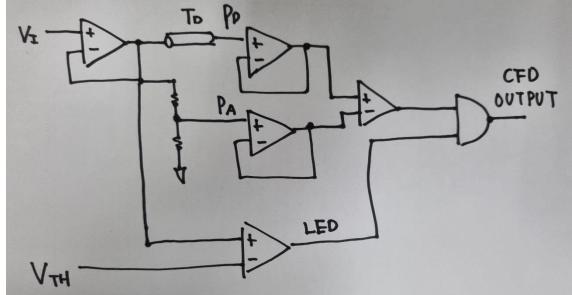
Pd : Delayed (by $1 - f \times Tr$)

Pa: Attenuated (by f)

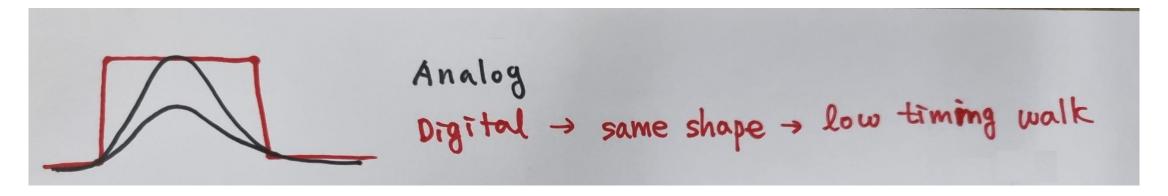
Then Pd and Pa have same

Voltage @ Th

Pd has voltage f x Vm @ Th

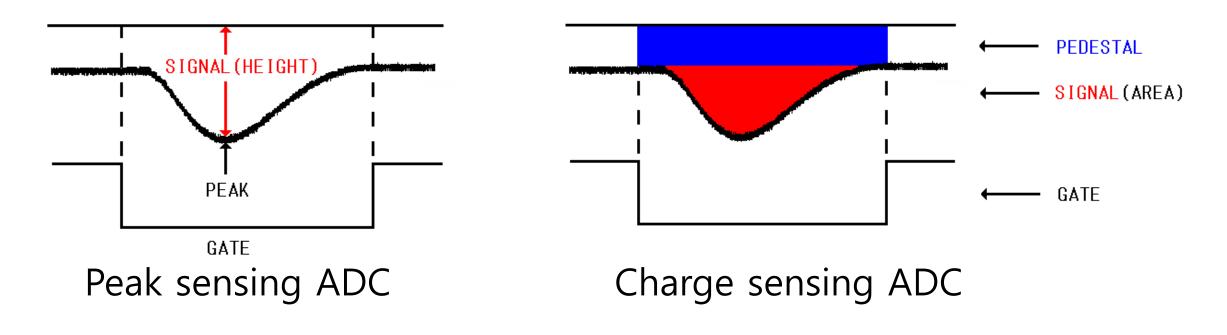


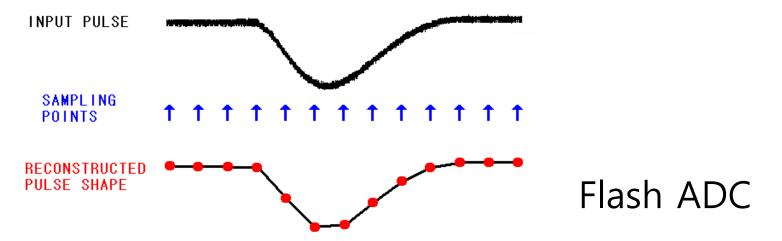
Logic(or Digital) Signal



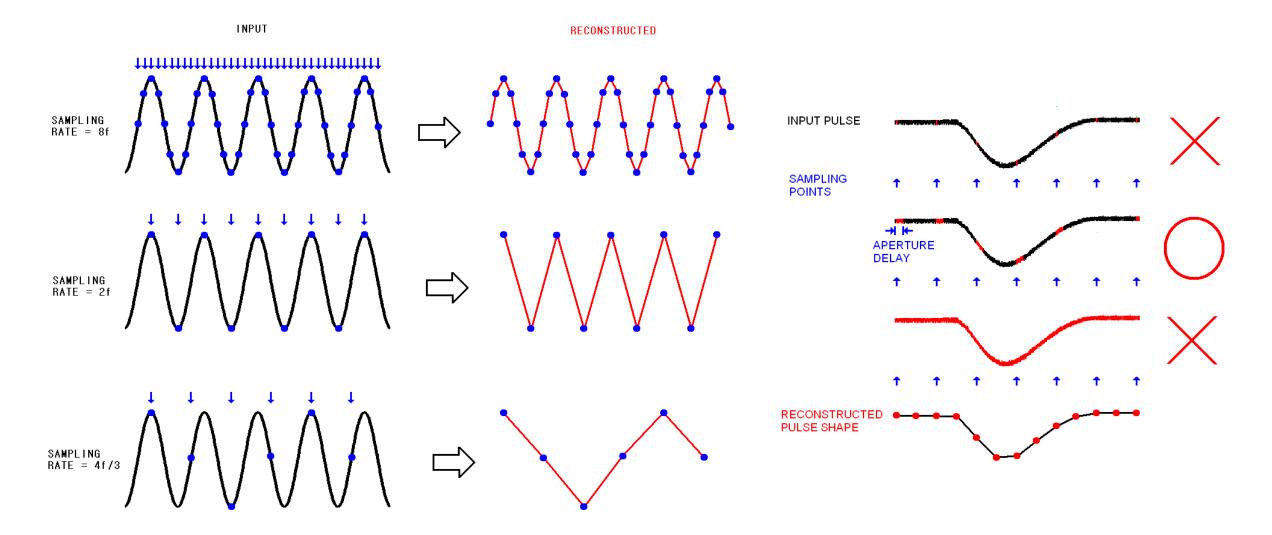
	Туре	Low (0)	High (1)
TTL/LVTTL	Single ended	< 0.8 V	> 2.0 V
NIM(slow)	Single ended	< 1.5 V	> 3.0 V
NIM(fast)	Single ended	> -200 mV(-4 mA)	< -600 mV(-12 mA)
ECL	Differential	< -1.48 V	> -0.81 V
LVDS	Differential	< 1.0 V	> 1.4 V

Analog to Digital Converter(ADC)

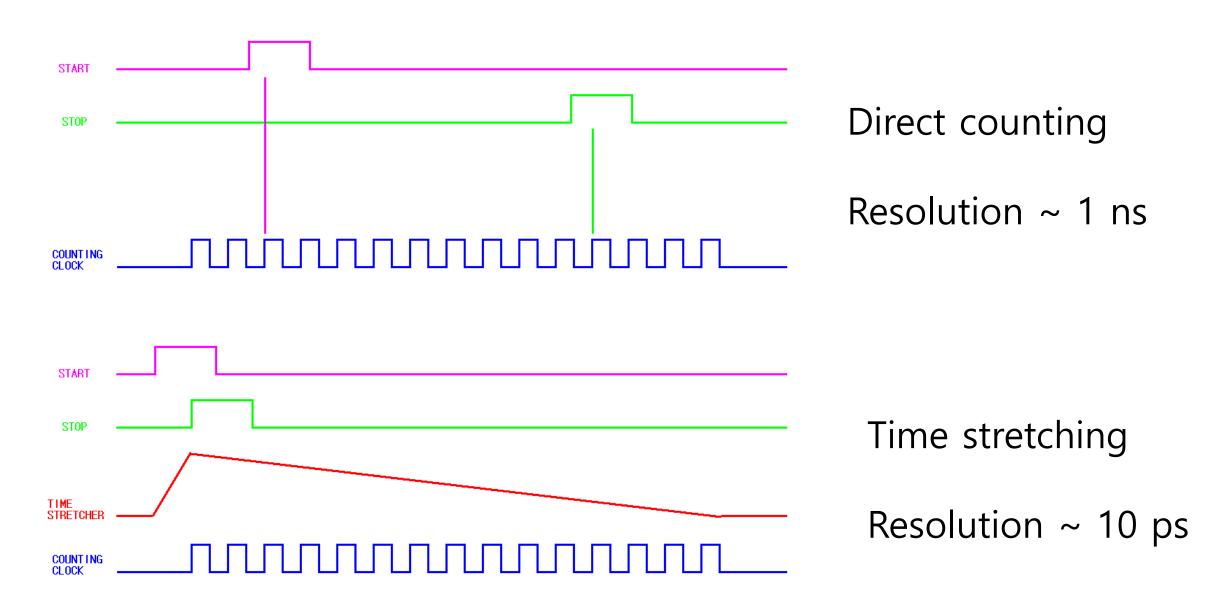




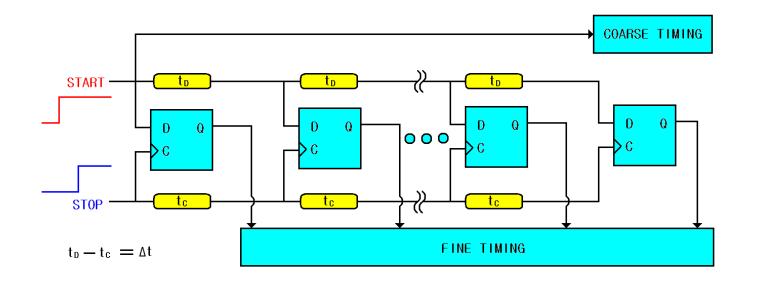
ADC sampling



Time to Digital Converter(TDC)

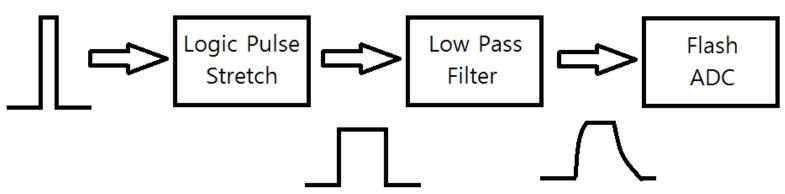


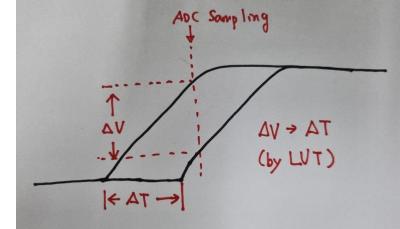
Time to Digital Converter



Time interpolation

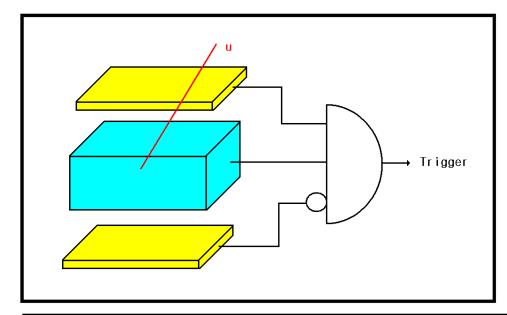
Resolution ~ 10 ps Multi-hit TDC

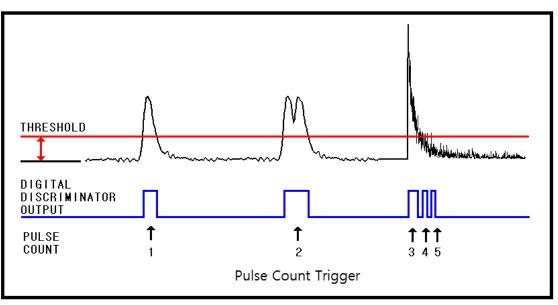


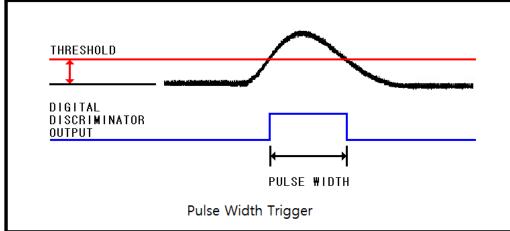


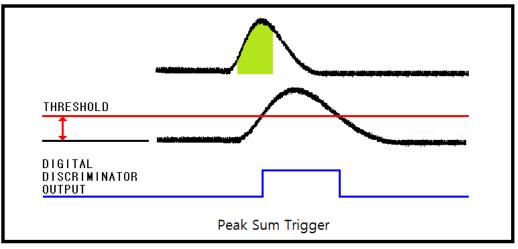
Pulse shaping TDC : resolution ~ 10 ps, multi-hit

Trigger

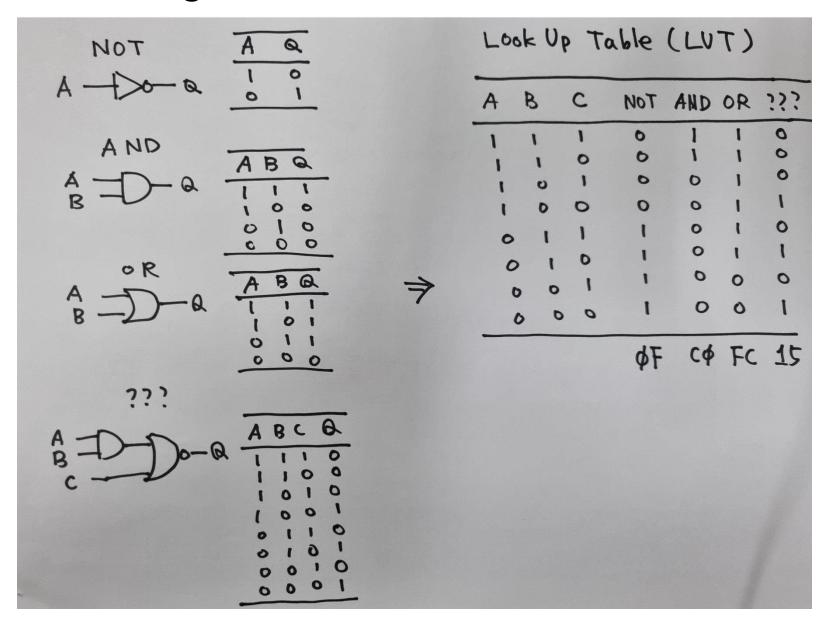




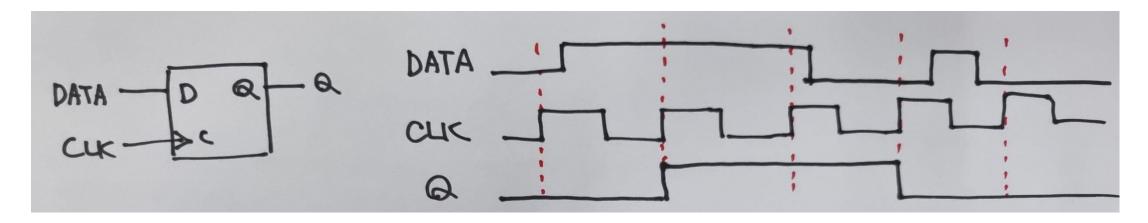


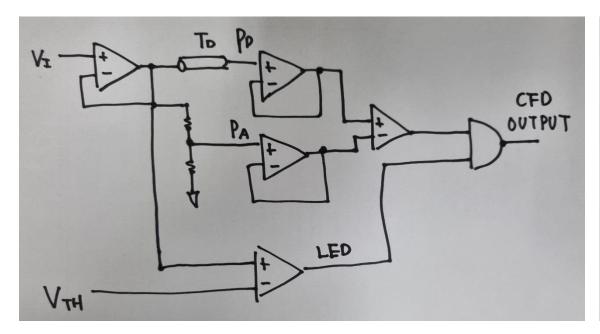


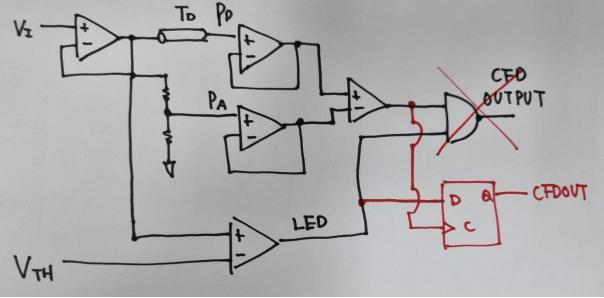
Combinational Logic



Sequential Logic



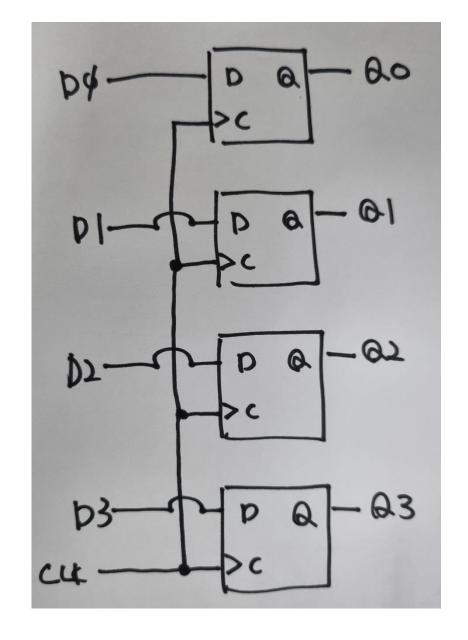




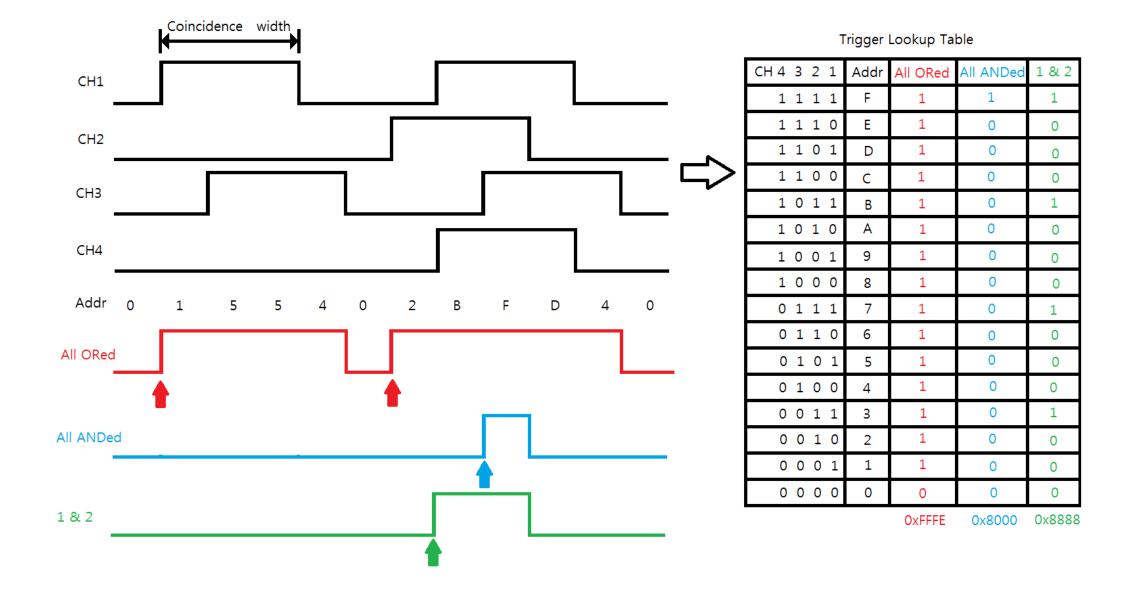
Examples of Sequential Logic

Q 0	Q 1	Q 2	Q 3	D 3	D 2	D 1	D 0
1	1	1	1	0	0	0	0
1	1	1	0	1	1	1	1
1	1	0	1	1	1	1	0
1	1	0	0	1	1	0	1
1	0	1	1	1	1	0	0
1	0	1	0	1	0	1	1
1	0	0	1	1	0	1	0
1	0	0	0	1	0	0	1
0	1	1	1	1	0	0	0
0	1	1	0	0	1	1	1
0	1	0	1	0	1	1	0
0	1	0	0	0	1	0	1
0	0	1	1	0	1	0	0
0	0	1	0	0	0	1	1
0	0	0	1	0	0	1	0
0	0	0	0	0	0	0	1

Q 0	Q 1	Q 2	Q 3	D 3	D 2	D 1	D 0
1	1	1	1	0	0	0	0
1	1	1	0	0	0	0	0
1	1	0	1	0	0	0	0
1	1	0	0	0	0	0	0
1	0	1	1	0	0	0	0
1	0	1	0	0	0	0	0
1	0	0	1	0	0	0	0
1	0	0	0	1	0	0	1
0	1	1	1	1	0	0	0
0	1	1	0	0	1	1	1
0	1	0	1	0	1	1	0
0	1	0	0	0	1	0	1
0	0	1	1	0	1	0	0
0	0	1	0	0	0	1	1
0	0	0	1	0	0	1	0
0	0	0	0	0	0	0	1



Trigger by combination



Data Acquisition







VME





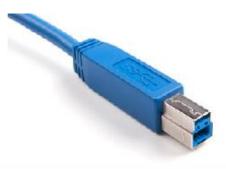
Standard

Custom

Data Acquisition



Ethernet: 125 MB/s max, ~30 MB/s typically

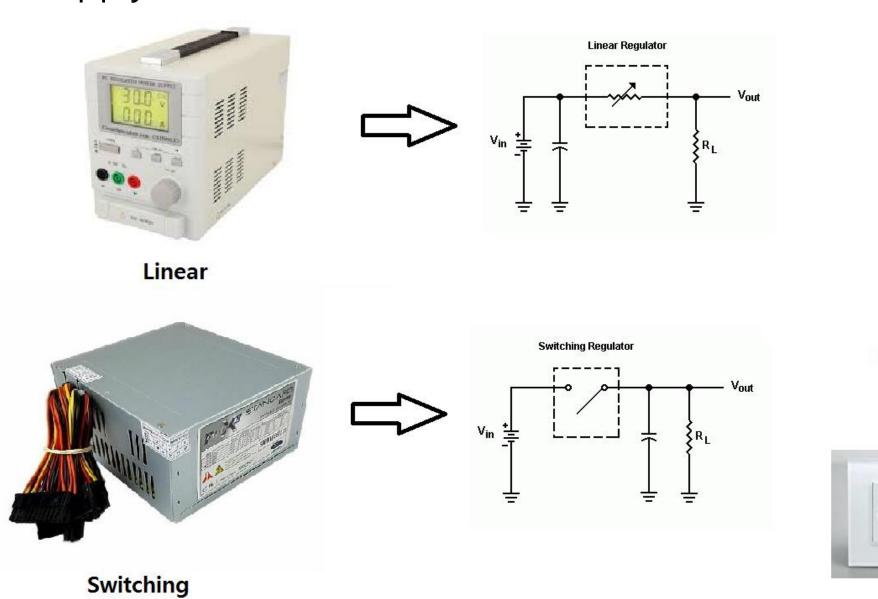


USB: 500 MB/s max, ~100 MB/s typically

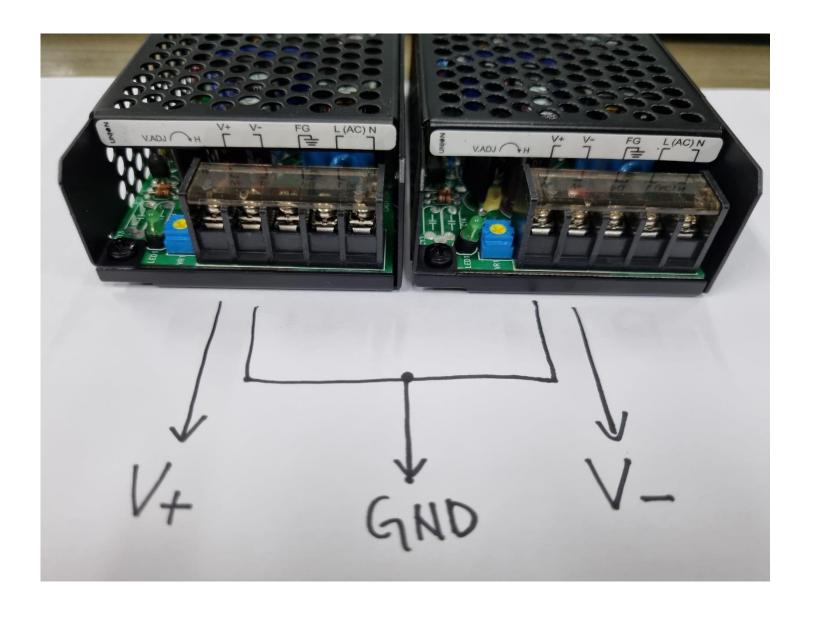


PCI: 63 GB/s max, ~??? typically

Power Supply



Power Supply Example



1. L, N to



- 2. FG to GND
- 3. Check FG & Vare not shorted
- 4. Variation:
 V- to GND
 GND to V1
 V+ to V1 + V2
 even if V1 is HV!

Example of electronics board : Gamma ray counter board



- 1. Pin PD to detect Gamma ray directly
- 2. Charge sensitive preamplifier
- 3. CR-RC2 shaping amplifier
- 4. Leading edge discriminator
- 5. MCU for counting logic
- 6. USB2 interface
- 7. GPS

Electronics board manufacturing process

- 1. Conceptual design and colleting parts
- 2. Draw schematics
- 3. Draw Printed Circuit Board(PCB) layout
- 4. Solder and assemble parts on PCB
- 5. Write Firmware(MCU, FPGA ...)
- 6. Write Software
- 7. Test and Debug

